2SC3130

Silicon NPN epitaxial planer type

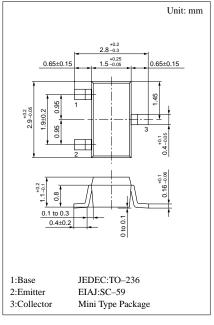
For high-frequency amplification/oscillation/mixing

Features

- High transition frequency f_T.
- ullet Small collector output capacitance C_{ob} and common base reverse transfer capacitance C_{rb} .
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

| Parameter | Symbol | Ratings | Unit |
|------------------------------|----------------|--------------------------|------|
| Collector to base voltage | V_{CBO} | 15 | V |
| Collector to emitter voltage | V_{CEO} | 10 | V |
| Emitter to base voltage | V_{EBO} | 3 | V |
| Collector current | I_{C} | 50 | mA |
| Collector power dissipation | P_{C} | 150 | mW |
| Junction temperature | T _j | 150 | °C |
| Storage temperature | $T_{\rm stg}$ | −55 ~ +150 | °C |



Marking symbol: 1S

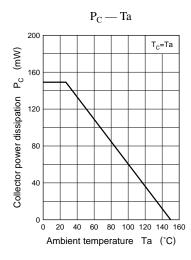
Electrical Characteristics (Ta=25°C)

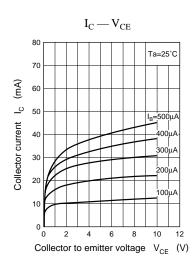
| Parameter | Symbol | Conditions min | | typ | max | Unit |
|---|----------------------|--|------|------|-----|------|
| Collector cutoff current | I_{CBO} | $V_{CB} = 10V, I_{E} = 0$ | | | 1 | μΑ |
| Collector to emitter voltage | V _{CEO} | $I_C = 2mA, I_B = 0$ | | | | V |
| Emitter to base voltage | V _{EBO} | $I_{\rm E} = 10 \mu A, I_{\rm C} = 0$ | 3 | | | V |
| Forward current transfer ratio | h _{FE} * | $V_{CE} = 4V$, $I_C = 5mA$ | 75 | 200 | 400 | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_C = 20\text{mA}, I_B = 4\text{mA}$ | | | 0.5 | V |
| Transition frequency | f_T | $V_{CB} = 4V$, $I_E = -5mA$, $f = 200MHz$ | 1.4 | 1.9 | 2.5 | GHz |
| Collector output capacitance | C _{ob} | $V_{CB} = 4V, I_{E} = 0, f = 1MHz$ | | 1.4 | | pF |
| Base time constant | $r_{bb}' \cdot C_C$ | $V_{CB} = 4V$, $I_E = -5mA$, $f = 31.9MHz$ | | 11 | | ps |
| Common emitter reverse transfer capacitance | C _{rb} | $V_{CB} = 4V, I_{E} = 0, f = 1MHz$ | | 0.45 | | pF |
| h _{FE} ratio | $\Delta h_{ m FE}$ | $\frac{V_{CE} = 4V, I_C = 100\mu A}{V_{CE} = 4V, I_C = 5mA}$ | 0.75 | | 1.6 | |

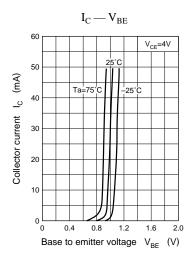
*h_{FE} Rank classification

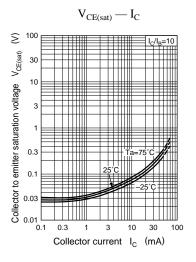
| Rank | P | Q | R |
|-------------------|----------|-----------|-----------|
| h_{FE} | 75 ~ 130 | 110 ~ 220 | 200 ~ 400 |
| Marking Symbol | 1SP | 1SQ | 1SR |

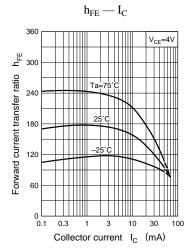
Transistor 2SC3130

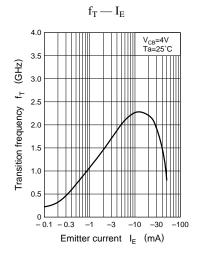


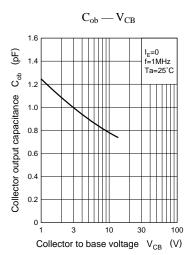












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